COMPLEMENTARY SILICON POWER TRANSISTORS

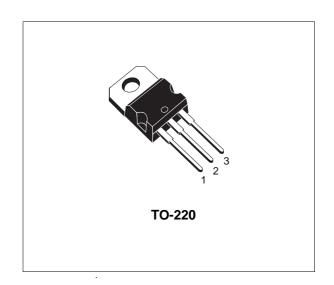
- SGS-THOMSON PREFERRED SALESTYPES
- COMPLEMENTARY PNP NPN DEVICES

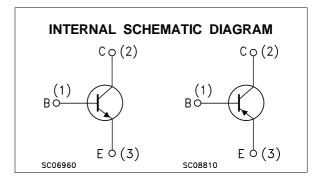
DESCRIPTION

The 2N6487 and 2N6488 are silicon epitaxial-base NPN transistors mounted in Jedec TO-220 plastic package.

They are inteded for use in power linear and low frequency switching applications.

The complementary PNP types are 2N6489 and 2N6490 respectively.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Unit		
		NPN		2N6487	2N6488	
		PNP	2N6489	2N6490		
V _{CBO}	Collector-Base Voltage (I _E = 0)		50	70	90	V
V _{CEX}	Collector-Emitter Voltage (V _{BE} =-1.5V,R _{BE} =100Ω)		50	70	90	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)		40	60	80	V
V _{EBO}	Emitter-Base Voltage (I _C = 0)			5		V
Ic	Collector Current			15		Α
Ι _Β	Base Current			5		Α
P _{tot}	Total Dissipation at T _c ≤ 25 °C		75			W
T _{stg}	Storage Temperature		-65 to 150			°C
Tj	Max. Operating Junction Temperature		150			°C

For PNP types voltage and current values are negative.

June 1997 1/4

THERMAL DATA

R _{thj-case}	Thermal Resistance Junction-case	Max	1.67	°C/W
$R_{thj-amb}$	Thermal Resistance Junction-ambient	Max	70	°C/W

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

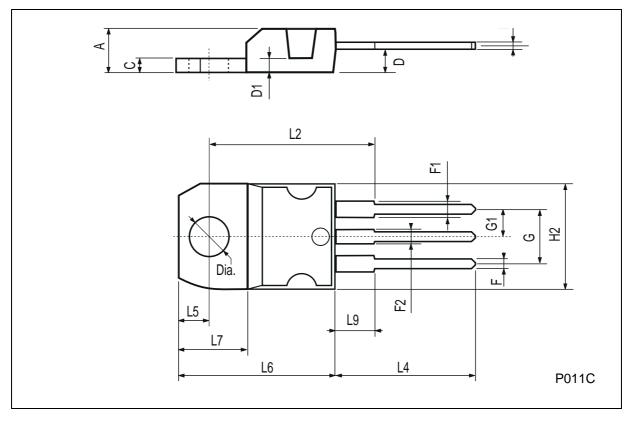
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CEX}	Collector Cut-off Current (V _{BE} = -1.5V)	for 2N6489			0.5 0.5 0.5	mA mA mA
		for 2N6487/2N6490 VCE = 60 V for 2N6488 VCE = 80 V			5 5	mA mA
I _{CER}	Collector Cut-off Current (R _{BE} = 100Ω)	for 2N6489			0.5 0.5 0.5	mA mA mA
I _{CEO}	Collector Cut-off Current (I _B = 0)	for 2N6489			1 1 1	mA mA mA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5 V			1	mA
$V_{\text{CEO(sus)}}^*$	Collector-Emitter Sustaining Voltage	I _C = 200 mA for 2N6489 for 2N6487/2N6490 for 2N6488	40 60 80			V V V
V _{CER(sus)} *	Collector-Emitter Sustaining Voltage $(R_{BE} = 100\Omega)$	I _C = 200 mA for 2N6489 for 2N6487/2N6490 for 2N6488	45 65 85			V V
VCEX(sus)*	Collector-Emitter Sustaining Voltage (V _{BE} =-1.5V, R _{BE} =100Ω)	I _C = 200 mA for 2N6489 for 2N6487/2N6490 for 2N6488	50 70 90			V V V
$V_{CE(sat)^*}$	Collector-Emitter Saturation Voltage	I _C = 5 A I _B = 0.5 A I _C = 15 A I _B = 5 A			1.3 3.5	V V
V _{BE} *	Base-Emitter Voltage	Ic = 5 A			1.3 3.5	V V
h _{FE} *	DC Current Gain	I _C = 5 A V _{CE} = 4 V I _C = 15 A V _{CE} = 4 V	20 5		150	
h _{fe}	Small Signal Current Gain	$\label{eq:controller} \begin{array}{llllllllllllllllllllllllllllllllllll$	5 25			

^{*} Pulsed: Pulse duration = 300 μs, duty cycle 1.5 % For PNP types voltage and current values are negative.



TO-220 MECHANICAL DATA

DIM.	mm			inch			
DIIVI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	4.40		4.60	0.173		0.181	
С	1.23		1.32	0.048		0.051	
D	2.40		2.72	0.094		0.107	
D1		1.27			0.050		
Е	0.49		0.70	0.019		0.027	
F	0.61		0.88	0.024		0.034	
F1	1.14		1.70	0.044		0.067	
F2	1.14		1.70	0.044		0.067	
G	4.95		5.15	0.194		0.203	
G1	2.4		2.7	0.094		0.106	
H2	10.0		10.40	0.393		0.409	
L2		16.4			0.645		
L4	13.0		14.0	0.511		0.551	
L5	2.65		2.95	0.104		0.116	
L6	15.25		15.75	0.600		0.620	
L7	6.2		6.6	0.244		0.260	
L9	3.5		3.93	0.137	· ·	0.154	
DIA.	3.75		3.85	0.147		0.151	



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